NSN 5961-01-309-8678

Unitized Semiconductor Devices - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-309-8678 **Inclosure Material:** Plastic **Overall Length:** 0.1197 inches **Terminal Length:** 0.02165 inches **Overall Height:** 0.0412 inches **Overall Width:** 0.0551 inches **Function For Which Designed:** Switching Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-236ab **Component Name And Quantity:** 2 semiconductor device diode **Mounting Method: Terminal Semiconductor Material:** Silicon all semiconductor device diode Voltage Rating In Volts Per Characteristic: 70.0 reverse voltage, dc all semiconductor device diode **Current Rating Per Characteristic:** 200.00 milliamperes source cutoff current preset all semiconductor device diode **Power Rating Per Characteristic:** 350.0 milliwatts small-signal input power, common-collector absolute all semiconductor device diode **Special Features:** All semiconductor device diode junction pattern arrangement: pn **Terminal Type And Quantity:** 3 ribbon Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0